



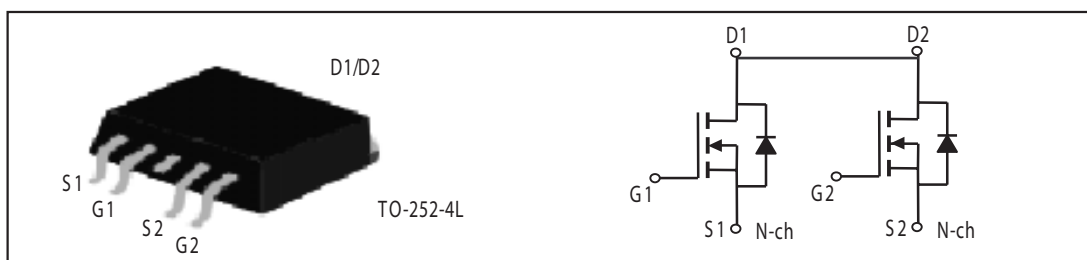
Dual N-Channel Enhancement Mode Field Effect Transistor

PRODUCT SUMMARY

V _{DSS}	I _D	R _{DS(ON)} (m Ω) Max
40V	16A	30 @ V _{GS} = 10V 40 @ V _{GS} = 4.5V

FEATURES

- Super high dense cell design for low R_{DS(ON)}.
- Rugged and reliable.
- TO252-4L package.



ABSOLUTE MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	40	V
Gate-Source Voltage		V _{GS}	±20	V
Drain Current-Continuous @ T _a	25°C	I _D	16	A
	70°C		13.8	A
-Pulsed ^a		I _{DM}	50	A
Drain-Source Diode Forward Current		I _S	8	A
Maximum Power Dissipation	T _a =25°C	P _D	11	W
	T _a =70°C		7.7	
Operating Junction and Storage Temperature Range		T _J , T _{STG}	-55 to 175	°C

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Case	R θ_{JC}	13.6	°C/W
Thermal Resistance, Junction-to-Ambient	R θ_{JA}	120	°C/W

STU402D

ELECTRICAL CHARACTERISTICS (TA =25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ ^c	Max	Unit
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	40			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =32V, V _{GS} =0V			1	uA
Gate-Body Leakage	I _{GSS}	V _{GS} =± 20V, V _{DS} =0V			±100	nA
ON CHARACTERISTICS ^b						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D = 250uA	1	1.8	3.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =8A		23	30	m-ohm
		V _{GS} = 4.5V, I _D =6A		32	40	m-ohm
On-State Drain Current	I _{D(ON)}	V _{DS} = 5V, V _{GS} = 4.5V	10			A
Forward Transconductance	g _{FS}	V _{DS} = 5V, I _D =8A		12		S
DYNAMIC CHARACTERISTICS ^c						
Input Capacitance	C _{ISS}	V _{DS} =25V, V _{GS} = 0V f =1.0MHz		770		pF
Output Capacitance	C _{OSS}			103		pF
Reverse Transfer Capacitance	C _{RSS}			65		pF
SWITCHING CHARACTERISTICS ^c						
Turn-On Delay Time	t _{D(ON)}	V _{DD} = 20V, I _D = 1A, V _{GS} = 10V, R _L = 20 ohm R _{GEN} = 6 ohm		13		ns
Rise Time	t _r			10		ns
Turn-Off Delay Time	t _{D(OFF)}			27		ns
Fall Time	t _f			6		ns
Total Gate Charge (10V)	Q _g	V _{DS} =28V, I _D = 8A, V _{GS} =10V		17		nC
Total Gate Charge (4.5V)	Q _g			8.7		nC
Gate-Source Charge	Q _{gs}			1.9		nC
Gate-Drain Charge	Q _{gd}			4.5		nC

STU402D

ELECTRICAL CHARACTERISTICS (T_c=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
DRAIN-SOURCE DIODE CHARACTERISTICS ^a						
Diode Forward Voltage	V _{SD}	V _{GS} = 0V, I _S = 8A		0.96	1.3	V

Notes

- a. Pulse Test: Pulse Width ≤ 300us, Duty Cycle ≤ 2%.
- b. Guaranteed by design, not subject to production testing.

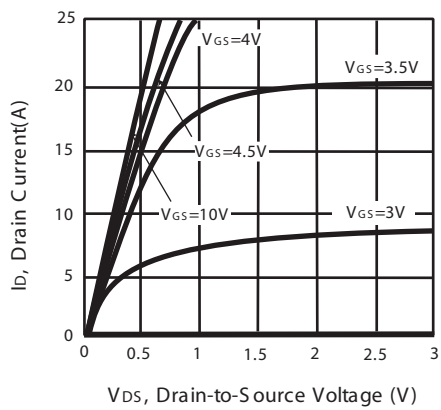


Figure 1. Output Characteristics

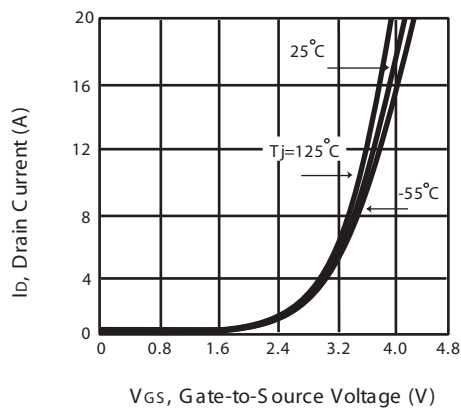


Figure 2. Transfer Characteristics

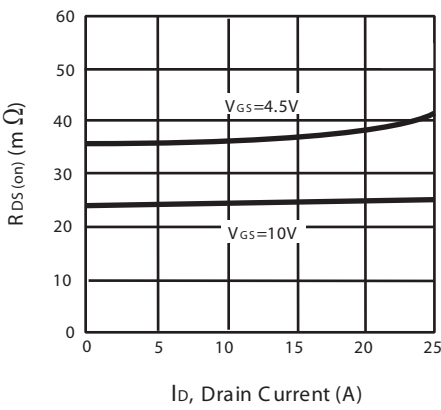


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

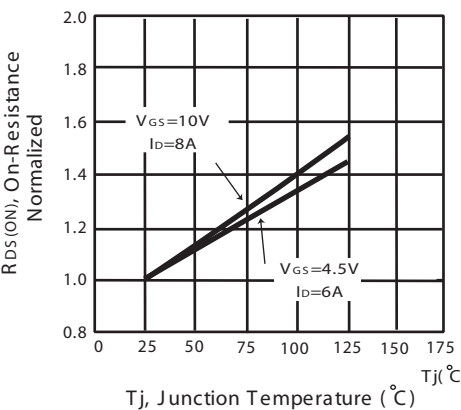


Figure 4. On-Resistance Variation with Drain Current and Temperature

STU402D

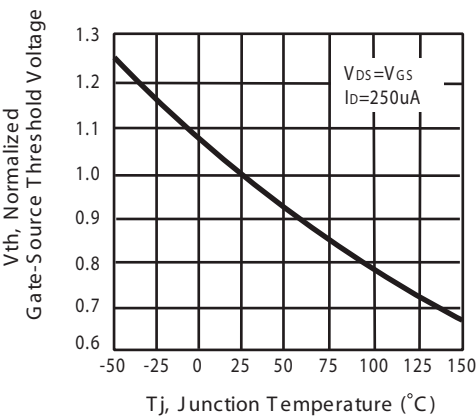


Figure 5. Gate Threshold Variation with Temperature

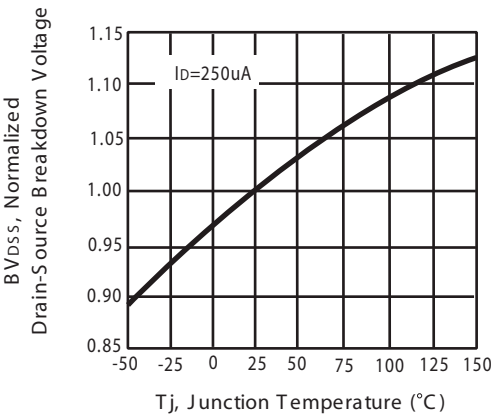


Figure 6. Breakdown Voltage Variation with Temperature

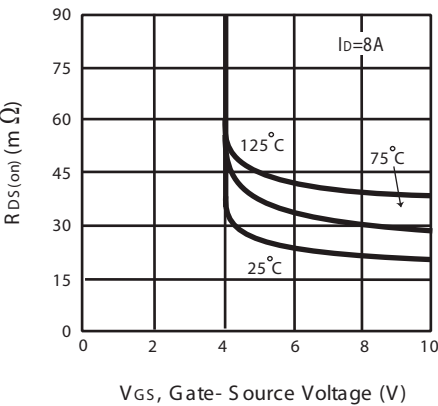


Figure 7. On-Resistance vs. Gate-Source Voltage

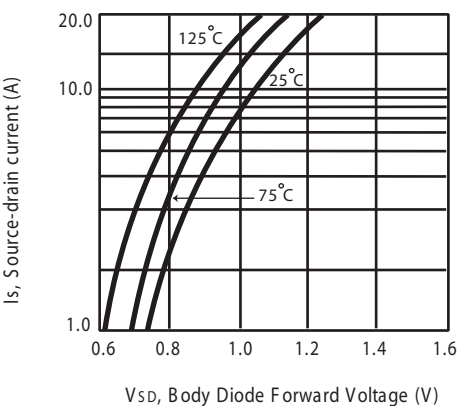


Figure 8. Body Diode Forward Voltage Variation with Source Current

STU402D

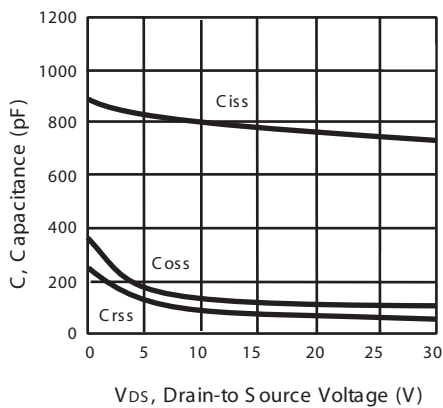


Figure 9. Capacitance

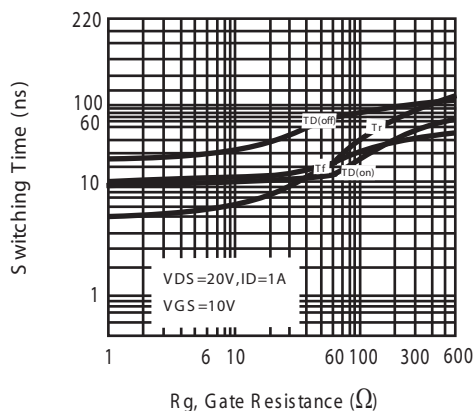
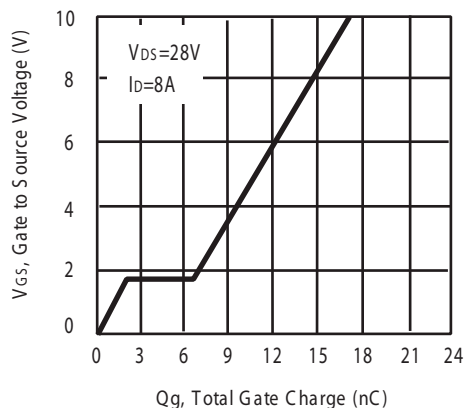


Figure 11. switching characteristics

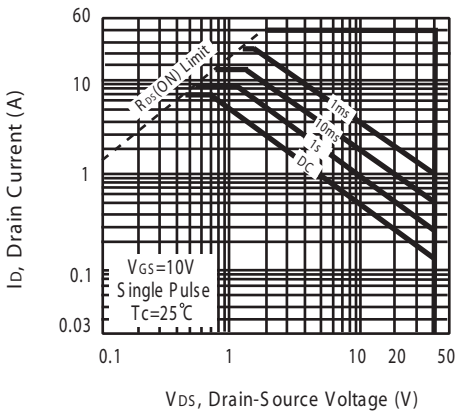


Figure 10. Maximum Safe Operating Area

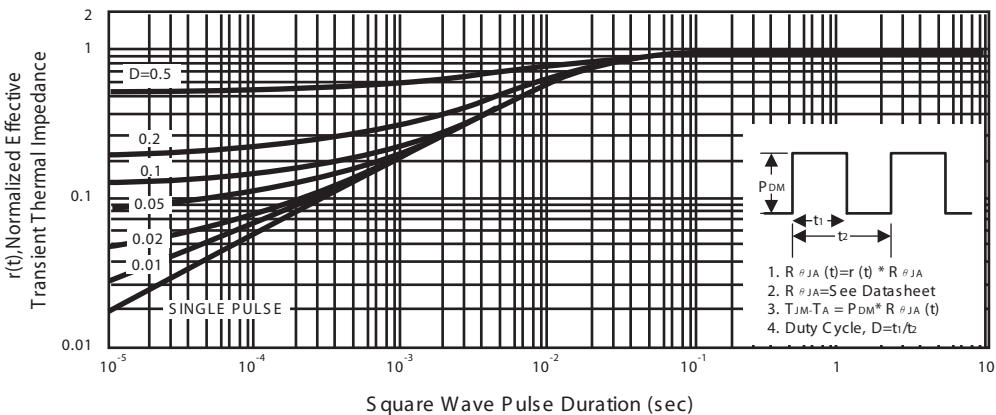
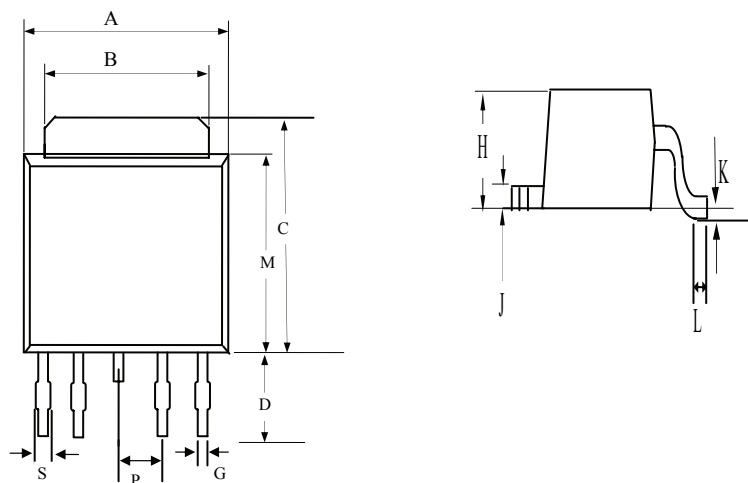


Figure 13. Normalized Thermal Transient Impedance Curve

STU402D

PACKAGE OUTLINE DIMENSIONS

TO-252-4L

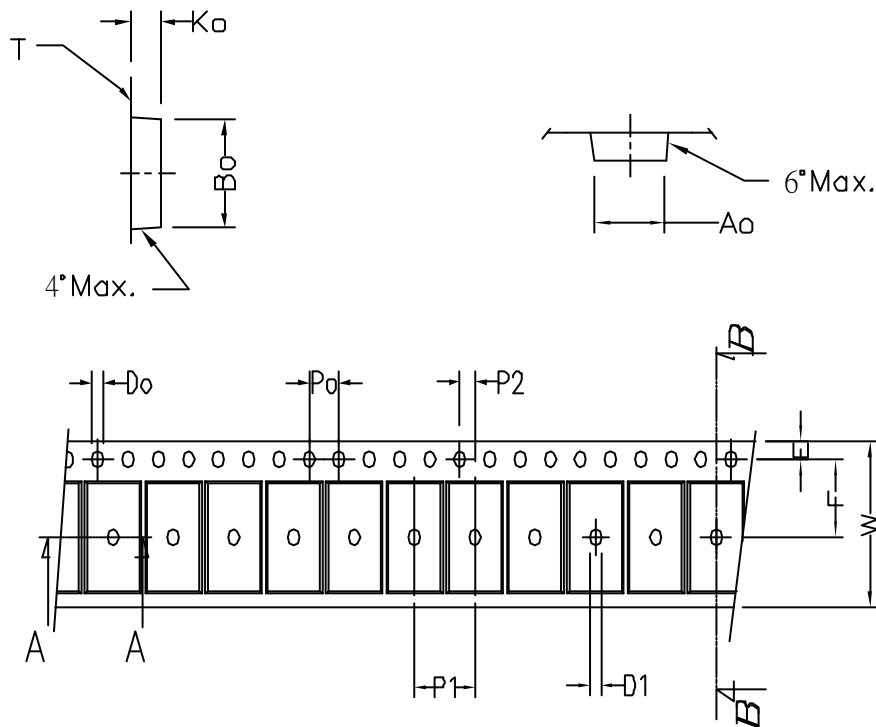


REF .	Millimeters	
	MIN	MAX
A	6.40	6.80
B	5.2	5.50
C	6.80	10.20
D	2.20	3.00
P	1.27 REF.	
S	0.50	0.80
G	0.40	0.60
H	2.20	2.40
J	0.45	0.60
K	0	0.15
L	0.90	1.50
M	5.40	5.80

STU402D

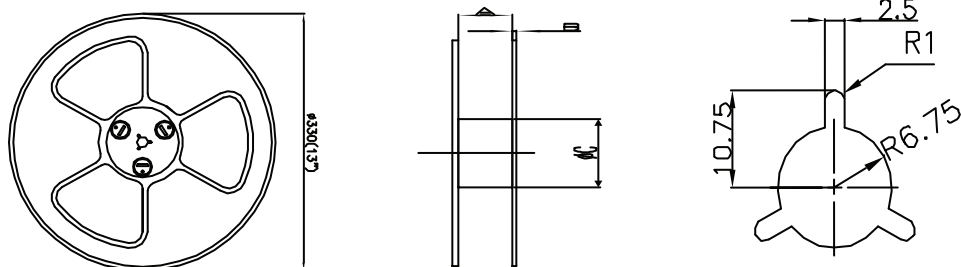
TO-252-4L Tape and Reel Data

TO-252-4L Carrier Tape



symbol	A_0	B_0	K_0	P_0	P_1	P_2	T
Spec	6.96 ± 0.1	10.49 ± 0.1	2.79 ± 0.1	4.0 ± 0.1	8.0 ± 0.10	2.0 ± 0.05	0.33 ± 0.013
symbol	E	F	D_0	D_1	W	$10P_0$	
Spec	1.75 ± 0.1	7.5 ± 0.05	1.55 ± 0.05	1.5 ± 0.25	16.0 ± 0.3	40.0 ± 0.2	

TO-252-4L Reel



UNIT:mm

Width of carrier tape	8	12	16	24	32	44	56
$A \pm 0.1$	9.4	13.4	17.4	25.4	33.4	45.4	57.4
B	2.3	2.3	2.3	2.3	2.3	2.3	2.3
ϕC	100	100	100	100	100	100	100